

PMEG3002AEL

30 V, 0.2 A very low V_F MEGA Schottky barrier rectifier in leadless ultra small SOD882 package

Rev. 02 — 15 January 2010

Product data sheet

1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier diode with an integrated guard ring for stress protection encapsulated in a SOD882 leadless ultra small plastic package.

1.2 Features

Forward current: 0.2 A

Reverse voltage: 30 V

- Very low forward voltage
- Leadless ultra small plastic package
- Power dissipation comparable to SOT23

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Low voltage rectification
- High efficiency DC-to-DC conversion
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		-	-	0.2	Α
V_R	reverse voltage		-	-	30	V



2. Pinning information

Table 2. Discrete pinning

Pin	Description	Simplified outline Symbol
1	cathode	<u>U</u>
2	anode	Top view 1 1 2 sym001 Bottom view 1 Top view 001aaa332

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package	ıckage					
	Name	Description	Version				
PMEG3002AEL	-	leadless ultra small plastic package; 2 terminals; body 1.0 \times 0.6 \times 0.5 mm	SOD882				

4. Marking

Table 4. Marking

Type number	Marking code
PMEG3002AEL	F3

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{R}	continuous reverse voltage			-	30	V
I _F	continuous forward current			-	0.2	Α
I _{FRM}	repetitive peak forward current	$t_p \leq 1 \text{ ms; } \delta \leq 0.25$		-	1	Α
I _{FSM}	non-repetitive peak forward current	$t_p = 8 \text{ ms square}$ wave		-	3	Α
Tj	junction temperature		[1]	-	150	°C
T _{amb}	operating ambient temperature		[1]	-65	+150	°C
T _{stg}	storage temperature			–65	+150	°C

[1] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and I_{F(AV)} rating will be available on request.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	500	K/W

^[1] Refer to SOD882 standard mounting conditions (footprint), FR4 with 60 μ m copper strip line.

7. Characteristics

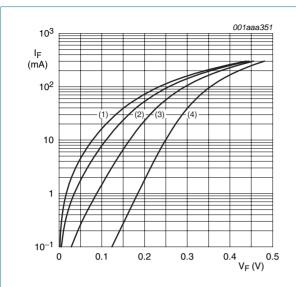
Table 7. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	continuous forward	see Figure 1;				
VO	voltage	$I_F = 0.1 \text{ mA}$	-	125	190	mV
		I _F = 1 mA	-	185	250 m	mV
		$I_F = 10 \text{ mA}$	-	250	300	mV
		$I_F = 100 \text{ mA}$	-	350	400	mV
		I _F = 200 mA	-	420	480	mV
I _R	continuous reverse	see Figure 2; [1]				
	current	V _R = 10 V	-	2.5	10	μΑ
		V _R = 30 V	-	10	50	μΑ
C _d	diode capacitance	$V_R = 1 \text{ V; } f = 1 \text{ MHz;}$ see Figure 3	-	17	25	pF

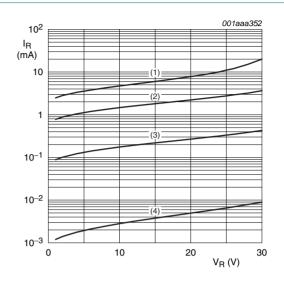
^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

^[2] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.



- (1) $T_j = 150 \, ^{\circ}C$
- (2) $T_i = 125 \, ^{\circ}\text{C}$
- (3) $T_i = 85 \, ^{\circ}C$
- (4) $T_i = 25 \, ^{\circ}C$

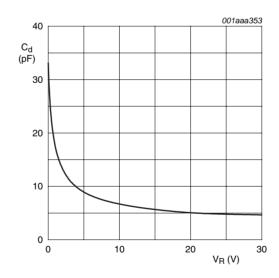
Forward current as a function of forward voltage; typical values



- (1) $T_j = 150 \, ^{\circ}C$
- (2) $T_i = 125 \, ^{\circ}C$
- (3) $T_i = 85 \, ^{\circ}C$
- (4) $T_j = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

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 $T_{amb} = 25 \, ^{\circ}C; f = 1 \, MHz$

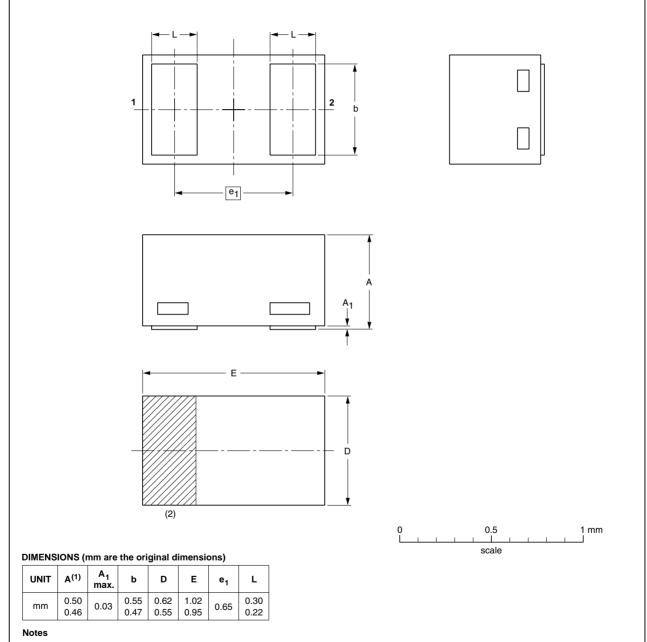
Product data sheet

Diode capacitance as a function of reverse voltage; typical values Fig 3.

8. Package outline

Leadless ultra small plastic package; 2 terminals; body 1.0 x 0.6 x 0.5 mm

SOD882



- 1. Including plating thickness
- 2. The marking bar indicates the cathode

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOD882					-03-04-16 03-04-17

Fig 4. Package outline



9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG3002AEL_2	20100115	Product data sheet	-	PMEG3002AEL_1
Modifications:		eet was changed to reflect w legal definitions and disc		
PMEG3002AEL_1	20040224	Product data	-	-

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PMEG3002AEL

0.2 A very low V_F MEGA Schottky barrier rectifier

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Date of release: 15 January 2010 Document identifier: PMEG3002AEL_2